

| | | | |
|-----------------------------------|---------------------------------------|---|-------------|
| Notice of References Cited | Application/Control No. 09/650,604 | Applicant(s)/Patent Under Reexamination KRUTSICK, THOMAS J. | |
| | Examiner A. Sefer | Art Unit 2826 | Page 1 of 1 |

U.S. PATENT DOCUMENTS

| * | | Document Number Country Code-Number-Kind Code | Date MM-YYYY | Name | Classification |
|---|---|--|-----------------|----------|----------------|
| | A | US-6,046,491 | 04-2000 | Tamagawa | 257/538 |
| | B | US-4,948,747 | 08-1990 | Pfiester | 437/60 |
| | C | US-5,804,857 | 09-1998 | Tsuji | 257/346 |
| | D | US-4,609,935 | 09-1986 | Kondo | 357/51 |
| | E | US- | | | |
| | F | US- | | | |
| | G | US- | | | |
| | H | US- | | | |
| | I | US- | | | |
| | J | US- | | | |
| | K | US- | | | |
| | L | US- | | | |
| | M | US- | | | |

FOREIGN PATENT DOCUMENTS

| * | | Document Number Country Code-Number-Kind Code | Date MM-YYYY | Country | Name | Classification |
|---|---|--|-----------------|---------|-----------------|----------------|
| | N | JP 57-100723 | 06-1982 | Japan | Mitsuyama et al | |
| | O | JP 1-130552 | 05-1998 | Japan | Tanaka et al | |
| | P | | | | | |
| | Q | | | | | |
| | R | | | | | |
| | S | | | | | |
| | T | | | | | |

NON-PATENT DOCUMENTS

| * | | Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages) |
|---|---|--|
| | U | D. Jaume et al., "High-Voltage Planar Devices Using Field Plate and Semi-Resistive Layers" IEEE Transactions on Electron Devices, VOL. 38, No. 7, July 1991. |
| | V | |
| | W | |
| | X | |

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.